

SCH2065S4

20A, 650V SiC Schottky Barrier Diode

Features

- Low Forward Voltage Drop: $V_F=1.3V$ (typical @ $I_F=20A$)
- Reverse Voltage: $V_{RRM}=650V$
- Avalanche Energy Rated
- High Surge Capability
- Low Power Loss and High Efficiency
- Silicon Carbide Substrate

Applications

- Switching Power Supply
- Solar Inverter
- Power Factor Correction
- Uninterruptible Power Supply

Description

The SCH2065S4 is a SiC schottky barrier diode. It is base on silicon carbide material, and its switching behavior is independent with temperature. The device has superfast recovery property and lower forward voltage drop, it can be used in switching power supply, solar inverter, PFC and UPS.

Package Type & internal Circuit



1. Cathode 2. Anode

Absolute Maximum Ratings per diode at $T_C=25^\circ C$ unless otherwise noted

Symbol	Parameter		Ratings	Unit
V_{RRM}	Peak Repetitive Reverse Voltage		650	V
V_{RWM}	Working Peak Reverse Voltage		650	V
V_R	DC Blocking Voltage		650	V
$I_{F(AV)}$	Average Rectified Forward Current	per diode at $T_C=125^\circ C$	20	A
I_{FSM}	Non-repetitive Peak Surge Current	$t_p=10ms$, half sine wave	120	A
		$t_p=200us$, square wave	480	A
P_D	Power Dissipation		183	W
T_J	Operating Junction Temperature Range		-55~+175	$^\circ C$
T_{STG}	Storage Temperature Range		-55~+175	$^\circ C$

Thermal Characteristics

Symbol	Parameter	Ratings	Unit
$R_{th(J-C)}$	Thermal Resistance, Junction to case	0.82	$^\circ C/W$

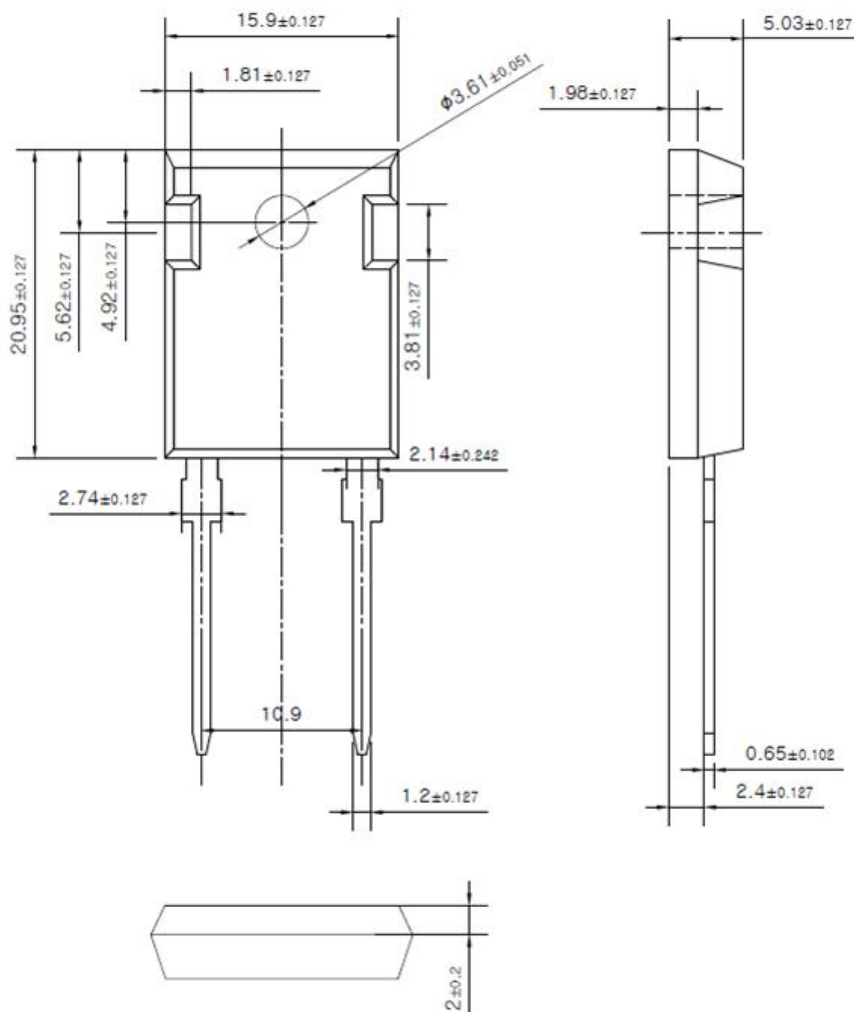
**Electrical Characteristics** per diode at $T_C=25\text{ }^{\circ}\text{C}$ unless otherwise noted

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
V_F	Forward Voltage Drop	$I_F=20\text{A}$	-	1.3	1.5	V
		$I_F=20\text{A}$, $T_C=125^{\circ}\text{C}$	-	1.4	1.7	V
I_R	Reverse Leakage Current	$V_R=650\text{V}$	-	-	200	μA
C	Total Capacitance	$V_R=0\text{V}$, $f=1\text{MHz}$	-	1210	-	pF
		$V_R=200\text{V}$, $f=1\text{MHz}$	-	124	-	
		$V_R=400\text{V}$, $f=1\text{MHz}$	-	90	-	
Q_C	Total Capacitive Charge	$V_R=400\text{V}$, $I_F=20\text{A}$, $di/dt=-200\text{A}/\mu\text{s}$	-	41	-	nC

Package Dimensions


TO-247

(Dimensions in Millimeters)



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